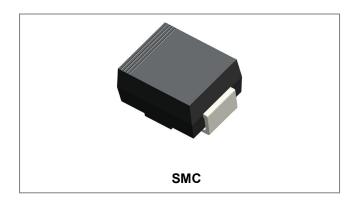






SK310 SCHOTTKY RECTIFIER



Features

- Small foot print, surface mountable
- Very low forward Voltage Drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings(limiting values, Tc =25°C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage	V_{RRM}	-		
Working Peak Reverse Voltage	V_{RWM}		100	V
DC Blocking Voltage	V_R			
Average Poetified Forward Current	1	50% duty cycle @T∟=100°C, rectangular	2	Α
Average Rectified Forward Current	IF (AV)	wave form	J	А
Peak One Cycle Non-Repetitive	lea	8.3ms, Half Sine pulse	110	Α
Surge Current	IFSM	o.siris, riali sirie puise	110	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 3A, Pulse, T _J = 25 °C	0.77	0.85	V
	V _{F2}	@ 3A, Pulse, T _J = 125 °C	0.63	0.80	V
Reverse Current*	I _{R1}	$@V_R = \text{rated } V_{R_1} T_J = 25 ^{\circ}\text{C}$	0.0001	0.6	mA
	I _{R2}	$@V_R = \text{rated } V_{R_1} T_J = 125 ^{\circ}\text{C}$	0.04	20.0	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C, f_{SIG} = 1MHz$	92	250	pF
Series Inductance	Ls	Measured lead to lead 5 mm from package body 8.0		-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse width < 300 µs, duty cycle < 2%





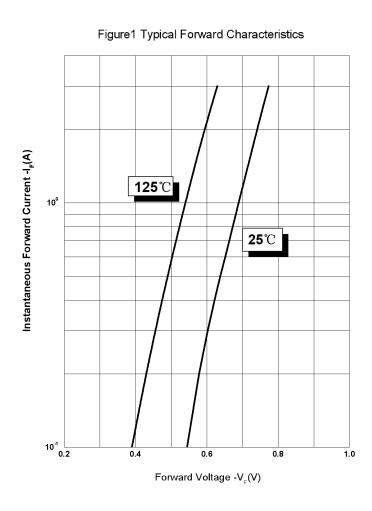


100

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Ambient	$R_{ heta JA}$	DC operation	55	°C/W
Approximate Weight	wt	-	0.21	g

Ratings and Characteristics Curves



10³ Instantaneous Reverse Current -IR(uA) 10² **125**℃ 10° 25℃ 10³ 20

40

Figure 2 Typical Reverse Characteristics

Figure 3 Typical Junction Capacitance 1000 Junction Capacitance -C_T (PF) 25℃ 100 10 **0** 2 10 Reverse Voltage -V_R(V)

Reverse Voltage -V_R(V)

• China - Germany - Korea - Singapore - United States •

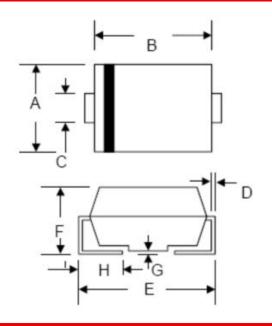
[•] http://www.smc-diodes.com - sales@ smc-diodes.com •







Mechanical Dimensions SMC



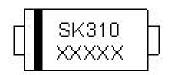
SYMBOL	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
А	5.59	6.22	0.220	0.245	
В	6.60	7.11	0.260	0.280	
С	2.75	3.25	0.108	0.128	
D	0.152	0.305	0.006	0.012	
E	7.75	8.25	0.305	0.325	
F	2.00	2.95	0.079	0.116	
G	0.051	0.203	0.002	0.008	
Н	0.76	1.60	0.030	0.063	

Ordering Information

Device	Package	Shipping
SK310	SMC (Pb-Free)	3000pcs / reel
SK310TR	SMC (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



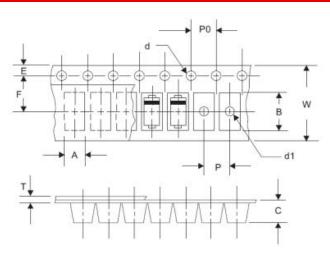
Where XXXXX is YYWWL

SK = Device Type 3 = Forward Current (3A) 10 = Reverse Voltage (100V) VV = Veer

YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification SMC



SYMBOL	Millimeters		
	Min.	Max.	
Α	3.70	3.90	
В	5.70	5.90	
С	2.32	2.52	
d	1.40	1.60	
E	1.40	1.60	
F	5.60	5.70	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
T	0.25	0.35	
W	11.80	12.20	

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •







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